# Semiconductor Device Modeling and Simulation

L4.02 Silvaco Atlas – Silvaco Syntax, Part 2

### Dragica Vasileska

Arizona State University



National Nanotechnology Coordinated Infrastructure



# Introduction to Silvaco ATLAS Tool

- 1. Some general comments
- 2. Deckbuild overview
- 3. ATLAS syntax
  - a) Structure specification
  - b) Materials models specification
  - c) Numerical method selection
  - d) Solution specification
  - e) Results analysis
- 4. ATLAS Extract description

# **ATLAS Syntax**

- The form of the input file statements is:
   <STATEMENT> <PARAMETER> = <VALUE>
   The parameter can be real, integer, character and logical
- The order in which the ATLAS commands occur is the following:
  - a) Structure specification: MESH, REGION, ELECTRODE, DOPING
  - b) Material models specification: MATERIAL, MODELS, CONTACT, INTERFACE
  - c) Numerical method selection: METHOD
  - d) Solution specification: LOG, SOLVE, LOAD, SAVE
  - e) Results analysis: EXTRACT, TONYPLOT

### **Numerical Method Selection**

- METHOD statement allows for several different choices of numerical method selection. The numerical methods that can be specified within the METHOD statement include
  - **GUMMEL →** Decoupled Gummel scheme which solves the necessary equations sequentially, providing linear convergence. Useful when there is weak coupling between the resultant equations.
  - NEWTON → Provides quadratic convergence and needs to be used for the case of strong coupling between the resultant equations.
  - **BLOCK NEWTON →** more efficient than NEWTON method

method gummel block newton method carriers=0

One can also alter the parameters relevant for the numerical solution procedure:

- CLIMIT.DD → Specifies minimum value of the concentration to be resolved by the solver.
- **DVMAX**  $\rightarrow$  Maximum potential update per iteration. Default value is 1V.

ATLAS allows for four different types of solutions to be calculated: **DC**, **AC**, **small signal** and **transient solutions**. The previously set bias at a given electrode is remembered and does not need to be set again.

#### **O** DC solution procedures and statements:

- A stable DC solution is obtained with the following two-step procedure:
  - Find good initial guess by solving equilibrium case (initial guess is found based on the local doping density)

#### solve init

• Step the voltage on a given electrode for a convergent solution:

```
solve vcollector=2.0
```

```
solve vbase=0.0 vstep=0.05 vfinal=1.0 name=base
```

 To overcome the problems with poor initial guess, one can use the TRAP statement, where MAXTRAPS is the maximum allowed number of trials (default value is 4)

```
method trap
solve init
solve vdrain=2.0
```

To generate a family of curves, use the following set of commands:

```
solve vgate=1.0 outf=solve_vgate1.str
solve vgate=2.0 outf=solve_vgate2.str
load infile=solve_vgate1.str
log outfile=mos_drain_sweep1.log
solve name=drain vdrain=0 vfinal=3.3 vstep=0.3
load infile=solve_vgate2.str
log outfile=mos_drain_sweep2.log
solve name=drain vdrain=0 vfinal=3.3 vstep=0.3
```

The **log** statement is used to save the Id/Vds curve from each gate voltage to separate file.

#### **O** AC solution procedures and statements:

The AC simulation is simply an extension to the DC simulation procedure. The **final result** of this analysis is the **conductance** and **capacitance** between each pair of electrodes. The two types of simulations are:

- Single frequency solution during a DC Ramp: solve vbase=0. vstep=0.05 vfinal=1 name=base AC freq=1e6
- Ramped frequency at a single bias:

solve vbase=0.7 ac freq=1e9 fstep=1e9 nfsteps=10
solve vbase=0.7 ac freq=1e6 fstep=2 mult.f nfsteps=10

#### **B** Transient solution procedures and statements:

For transient solutions, one needs to use piecewise-linear, exponential and sinusoidal bias functions. For a linear ramp, one needs to specify the following parameters: **TSTART**, **TSTOP**, **TSTEP** and **RAMPTIME**.

solve vgate=1.0 ramptime=1e-9 tstop=10e-9 tstep=1e-11

#### O Advanced solution procedures:

- Obtaining solutions around a breakdown point uses MAXTRAPS
- Using current boundary conditions

Instead of voltage, one can also specify current boundary conditions.

This is important, for example, when simulating BJTs:

```
solve ibase=1e-6
```

solve ibase=1e-6 istep=1e-6 ifinal=5e-6 name=base

The compliance parameter

This parameter is used to stop simulation when appropriate current level is reached.

```
solve vgate=1.0
solve name=drain vdrain=0 vfinal=2 vstep=0.2 \
compl=1e-6 cname=drain
```

• The curve trace capability – enables tracing out of complex IV curves

```
#This is the script for simulation of a diode
#
go victoryd
mesh space.mult=1.0
set x n = 0.5
set x p = 0.5
set x_tot = $x_n + $x_p
#
x.mesh loc=0.00 spac=0.01
x.mesh loc=$x n spac=0.0001
x.mesh loc=$x tot spac=0.01
#
v.mesh loc=0 spac=0.05
y.mesh loc=0.10 spac=0.05
```

```
# REGIONS AND ELECTRODES
region num=1 y.min=0 silicon
elect num=1 name=cathode y.min=0.0 y.max=0.1 x.min = 0 x.max = 0
elect num=2 name=anode y.min=0.0 y.max=0.1 x.min = $x_tot x.max = $x_tot
```

# DEVICE DOPING doping uniform n.type conc=1.e17 x.max = \$x\_n doping uniform p.type x.min = \$x\_n conc=1.e17 # MATERIAL CONTACT INTERFACE AND MODELS models temp=300 conmob fldmob

# INITIAL SOLUTION solve init method newton trap

save outfile = no\_bias.str
tonyplot no\_bias.str

log outf = IV.log solve vanode = 0 vstep = 0.05 vfinal = 0.8 name = anode

method newton trap

tonyplot IV.log

save outfile = final\_bias.str
tonyplot final\_bias.str

quit



Anode Voltage (V)

### **Electric field profile**



## **Conduction band profile**



## **Results Analysis**

Three types of outputs are produced by the ATLAS tool: *run-time outputs, log files* and *solution files*.

#### • Run-time outputs:

The various parameters displayed during the SOLVE statement are listed below:

**proj** → initial guess methodology used (previous, local or init)

- i, j,  $m \rightarrow$  iteration numbers of the solution and the solution method
  - i = outer loop iteration number
  - **j** = inner loop number for decoupled solutions
  - m = solution method used: G=Gummel, B=Block, N=Newton
- **x**, **rhs**  $\rightarrow$  norms of the equations being solved
- $(*) \rightarrow$  the error measure has met its tolerance

#### **O** Log files:

The **LOG** parameter is used to store the device characteristics calculated using ATLAS:

#### log outfile=<file\_name>

### **Run-Time Output**



# **Results Analysis (cont'd)**

#### Solution files:

The syntax to produce the solution files that can be used in conjunction with TonyPlot is:

```
load infile=<file_name_in>.str
solve ....
save outfile=<file_name_out>.str
```

#### Invoking TonyPlot

To create overlayed plots with TonyPlot, one needs to use the following command:

```
tonyplot -overlay file1.log file2.log
```

• To load structure files, containing mesh, doping profile information, etc., one can use the following statement:

```
tonyplot file.str -set mx.set iv.data
```

This command allows loading of the file called *"file.str"* and sets its display to a previous setup stored in the *"mx.set"* file, and then loads the file containing the *IV*-data.

### **Parameter Extraction**

- Using the EXTRACT command that operates on previously solved curve or structure file:
- To override the default of using open log file, the name of the file that needs to be used is specified in the following manner:

```
extract init infile="<file_name>"
```

• Parameters that can be extracted using this EXTRACT statement include: threshold voltage, cutoff frequency, etc. The extraction of the threshold voltage is accomplished with the following statement:

• Default file for saving results is **results.final**. The results can be stored in other file using the following options:

```
extract .... Datafile="<file_name>"
```

- 2) Using the Functions Menu in TonyPlot allows one to use saved data for postcomputation
- 3) Using the LOG statement for AC parameter extraction

## Parameter Extraction (cont'd)

- 1) The extract statement can be used in conjunction with:
  - Process extraction, after running Silvaco ATHENA simulator
  - **Device extraction**, after obtaining the electrical characteristics of the device structure being simulated



- Log-files: contain the electrical information, more precisely, the *IV*-data obtained via the ATLAS simulation process
- Structure files: contain the additional electrical information, such as electric field, electrostatic potential, etc.
- One can construct a *curve* using separate X and Y-axes. For each of the electrodes, one can choose one of the following:
   Voltage (v), Current (i), Capacitance (c), Conductance (g),
   Transient time for AC simulations (*time*), Frequency for AC simulations (*frequency*), Temperature (*temperature*), etc.

## Parameter Extraction (cont'd)

- 3) More in-depth description of the use of the EXTRACT statement:
- Curve, basic element in the extract statement. The syntax is as follows: extract name="curve\_name" curve(v."name", i."name") "curve\_name" = name of the curve to which one can refer to in later post-processing steps
- Axes manipulation:
  - algebra with a constant (multiplication, division)
  - operators application (abs, log, log10, sqrt)
- Curve manipulation primitives:

*min, max, ave, minslope, maxslope, slope, xintercept, yintercept, x.val* from curve where *y.val=Y* (*val.occno=1*, would mean first occurrence of the preset condition)

• **Example:** Find max  $\beta = I_C/I_B$  vs.  $I_C$ 

extract "maxbeta" max(curve(i."colector", i."colector"/i."base")

# Summary

- In this lecture we completed the discussion on basic Silvaco syntax. We discussed:
  - Numerical Methods selection
  - Solution specification
  - Types of analyses
  - Parameter extraction